


TRANSMITTAL

Electronic Version v1.1

Stylesheet Version v1.1.0

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| Title of Invention | METHOD OF FABRICATING A CMOS DEVICE WITH DUAL METAL GATE ELECTRODES | |
| Application Number : | 10/826665 |  |
| Date : | 2004-04-16 | |
| First Named Applicant: | PARK CHANG SEO | |
| Confirmation Number: | 9608 | |
| Attorney Docket Number: | 61472-0308425 | |
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| Submitted By: | | Elec. Sign. |
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| Documents being submitted: | Files |
|----------------------------|---|
| us-ids | 061472-0308425-usidst.xml us-ids.dtd us-ids.xsl |
| Comments | |